8-bit Proprietary Microcontrollers

CMOS

F²MC-8L MB89210 Series

MB89215/F217/P215/PV210

■ DESCRIPTION

The MB89210 series is a one-chip microcontroller that features a compact instruction set and contains a range of peripheral functions including timers, a serial interface, A/D converters and external interrupts.

■ FEATURES

• F2MC-8L CPU core

Maximum memory spaces : 64 Kbytes

Minimum instruction execution time : 0.32 μs to 5.12 μs (at 12.5 MHz)
 Interrupt processing time : 2.88 μs to 46.08 μs (at 12.5 MHz)

• I/O port : Max 22

• 21-bit time base timer

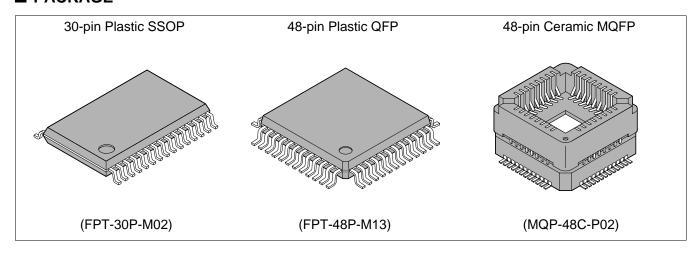
• 8-bit PWM timer

• 8-/16-bit capture timer/counter: 2 ch

Watchdog timer12-bit PPG timer

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■ PACKAGE





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• 10-bit A/D converter: 8 ch

• LIN-UART

• 8-bit serial I/O

• External Interrupt : 3 ch

• External or CR (built-in) oscillation clock, switchable

• Low power consumption modes (stop modes, sleep modes)

• Package: SSOP-30,QFP-48, MQFP-48

CMOS technology

■ PRODUCT LINEUP

	Part number								
Para	ameter	MB89215	MB89F217	MB89P215	MB89PV210				
Туре	9	For mass products (Mask ROM product)	Flash products (Flash ROM product)	One-time product (for small-scale production)	Piggy back/ Evaluation product (for development)				
RON	Л capacity	16 Kbyte (Built-in ROM)	32 Kbyte (Built-in Flash memory)	16 Kbyte (Built-in PROM)	32 Kbyte (External EPROM)				
RAM	1 capacity	512 byte	1 Kbyte	512 byte	2 Kbyte				
CPL	J functions	Number of basic instructions: 136Instruction bit length: 8 bitsInstruction length: 1 to 3 bytesData bit length: 1, 8, and 16 bitsMinimum instruction execution time: 0.32 μs to 5.12 μs (at 12.5 MHz)Interruption processing time: 2.88 μs to 46.08 μs (at 12.5 MHz)							
	Ports	General purpose I/O × 1	port × 21 (also usable	as resources) Genera	al purpose input port				
	21-bit time base timer	21 bits Interrupt cycle: at 10	MHz (0.82 ms,3.3 m	s,26.2 ms,419.4 ms)					
	Watchdog timer	Reset generation cycle : at 10 MHz (Min 419.4 ms)							
	8-bit PWM timer	8-bit interval timer operation (supports square wave output, operating clock period : $0.4~\mu s$ to $25.6~\mu s$) 8-bit resolution PWM operation (conversion period : $102.4~\mu s$ to $26.84~\mu s$)							
Peripheral functions	8/16-bit capture timer counter	or 16-bit capture time Capable of event cou	8-bit capture timer/counter × 1 channel + 8-bit timer or 16-bit capture timer/counter × 1 channel Capable of event count operation and square wave output using external clock inpur with 8-bit timer 0 or 16-bit counter						
əripheral	LIN-UART	setting over 30,000 d	ull duplex, Synchronous/asynchronous transfer (with start/stop bit), Capable of etting over 30,000 different baud rates using a 15-bit reload counter upport for the LIN protocol, slave nodes, and LIN synch break/sync field detection						
l A	8-bit serial I/O	8-bit length, Selectab Transfer clock (0.8 μ							
	12-bit PPG timer	Output requency : Se	electable pulth width a	and cycle (Cycle: 1.6	μs to 419.3 ms)				
	External interrupt circuit	3-channel (interrupt vector, request flag, requesr output acceptance) Edge selectable (selectable rising, falling or both edge) Can be use for recovery from stop or sleep mode (edge detection also available in stop mode).							
	A/D converter	10-bit accurasy \times 8-channel A/D conversion function (conversion time : 15.2 μ s/10 MHz) Continuous activation by an 8-/16-bit timer/counter output or time base timer output capable.							
Stan	ndby mode		Sleep mode a	nd Stop mode					
<u> </u>	rating voltage *	3.5 V to 5.5 V	3.5 V to 5.5 V	3.5 V to 5.5 V	3.5 V to 5.5 V				
CR(I	built-in) oscillator	Yes	Yes	Yes	No				

^{*:} The minimum operating voltage varies with the operating frequency, the function and the connected ICE.

Note: Unless otherwise stated, clock periods and conversion times are for 10 MHz operation with the internal clock operating at maximum speed.

■ PACKAGES AND CORRESPONDING PRODUCTS

Package	MB89215	MB89F217	MB89P215	MB89PV210
FPT-30P-M02	0	×	0	X *1
FPT-48P-M13	0	0	×	X *2
MQP-48C-P02	×	×	×	0
Power supply pins	Vcc,Vss × 2	Vcc, Vss × 3, AVcc, AVss	Vcc,Vss × 2	Vcc, Vss × 2, AVcc, AVss

O:Yes \times :No

*1 : Adapter for 48-pin to 30-pin conversion (manufactured by Sunhayato Corp.)

Part number: 48QF-30SOP-8L

Inquiry: Sunhayato Corp. TEL: (81)-3-3984-7791

FAX: (81)-3-3971-0535 E-mail: adapter@sunhayato.co.jp

*2: Adapter for 48-pin (EVA) to 48-pin (MASK/FLASH) conversion.

Part number : Under development.

■ DIFFERENCES AMONG PRODUCTS

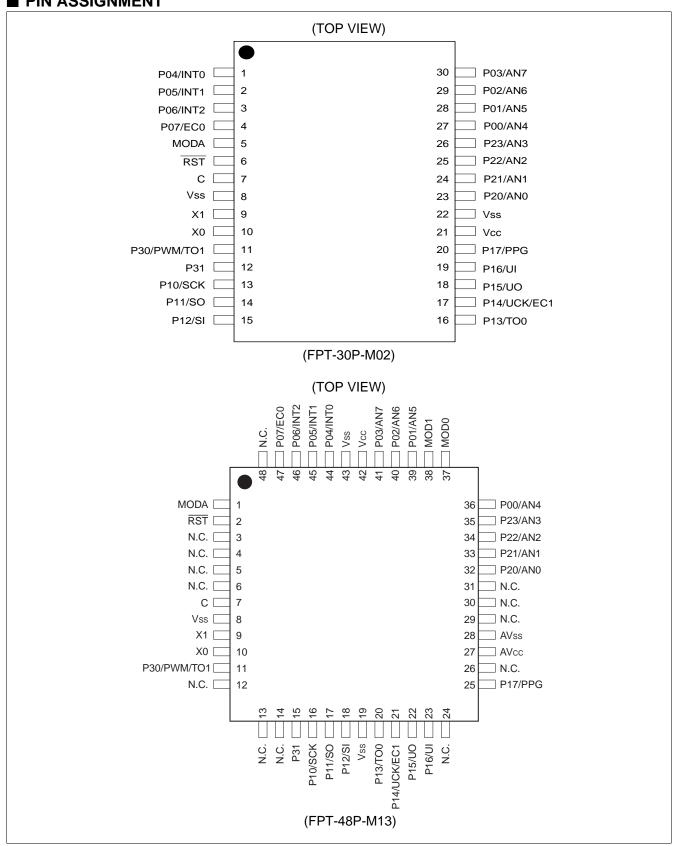
1. Memory space

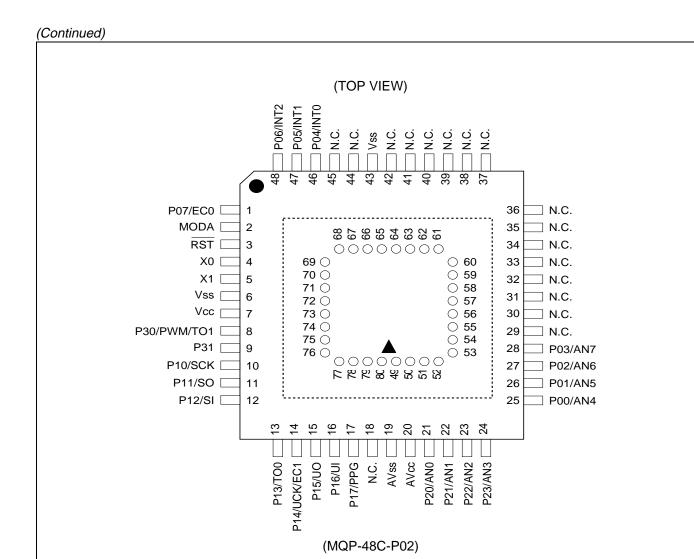
When this product is used in a piggy-back or other evaluation configuration, it is necessary to carefully confirm the differences between the model being used and the product it is evaluating.

2. Current Consumption

- On the MB89PV210, the additional current consumed by the EPROM is added at the connecting socket on the back side.
- When operating at low speed, the current consumption in the one-time PROM or EPROM models is greater than on the mask ROM models. However, current consumption in sleep or stop modes is identical. However, in sleep/stop mode the current consumption is the same.

■ PIN ASSIGNMENT





Pin no.	Pin						
49	Vpp	57	N.C.	65	04	73	OE
50	A12	58	A2	66	O5	74	N.C.
51	A7	59	A1	67	O6	75	A11
52	A6	60	A0	68	07	76	A9
53	A5	61	01	69	O8	77	A8
54	A4	62	O2	70	CE	78	A13
55	А3	63	O3	71	A10	79	A14
56	N.C.	64	Vss	72	N.C.	80	Vcc

N.C.: Internal connection only. Not for use.

■ PIN DESCRIPTIONS

	Pin no.		Circuit		
SSOP*1	QFP*2	MQFP*3	Pin name	type	Function
10	10	4	X0	А	Connecting pins to crystal oscillator or other oscillator.
9	9	5	X1		When using ecternal clock, input to X0 and X1 is left open.
_	37	_	MOD0	C/D ₁ *4	Input pins for memory access mode setting. Connect directly to Vss.
_	38		MOD1	C/D1 *	Input pins for memory access mode setting. Connect directly to Vss.
5	1	2	MODA	C/D ₂ *5	Input pins for memory access mode setting. Connect directly to Vss.
6	2	3	RST	E	Reset I/O pin. This pin has pull-up resistance with N-ch open drain or hysteresis input. At an internal reset request, an "L" signal is output. An "L" level input initializes the internal circuits.
27 to 30	36, 39 to 41	25 to 28	P00/AN4 to P03/AN7	G	General purpose I/O port. Hysteresis input. These pins also functions as the analog input of A/D converter.
1 to 3	44 to 46	46 to 48	P04/INT0 to P06/INT2		General purpose I/O port. These pins also functions as the external interrupt input. Hysteresis input.
4	47	1	P07/EC0		General purpose I/O port. This pin also functions as external clock of 8-/16-bit capture timer/counter 0 or capture input pin. Hysteresis input.
13	16	10	P10/SCK		General purpose I/O port. This pin also functions as clock input/output pin of serial I/O. Hysteresis input.
14	17	11	P11/SO		General purpose I/O port. This pin also functions as the data output pin of serial I/O. Hysteresis input.
15	18	12	P12/SI	F	General purpose I/O port. This pin also functions as the data input pin of serial I/O. Hysteresis input.
16	20	13	P13/TO0		General purpose I/O port. This pin also functions as the output pin of 8-/16-bit capture timer/counter 0. Hysteresis input.
17	21	14	P14/UCK/ EC1		General purpose I/O port. This pin also functions as the clock input/output pin of LIN-UART and the external clock of 8-/16-bit capture timer/counter 1 or capture input pin. Hysteresis input.
18	22	15	P15/UO		General purpose I/O port. This pin also functions as the data output pin of LIN-UART. Hysteresis input

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	Pin no.		Circu		Function	
SSOP*1	QFP*2	MQFP*3	Pin name	type	Function	
19	23	16	P16/UI	Н	General purpose I/O port. This pin also functions as the data input pin of LIN-UART. General port input is hysteresis and resource input is CMOS.	
20	25	17	P17/PPG	F	General purpose I/O port. This pin also functions as 12-bit PPG timer output. Hysteresis input.	
23 to 26	32 to 35	21 to 24	P20/AN0 to P23/AN3	G	General purpose I/O port. Shared for A/D converter analog input pin. Hysteresis input.	
11	11	8	P30/PWM/ TO1	F	General purpose I/O port. This pin also functions as the output pin of 8-bit PWM and 8-/ 16-bit capture timer/counter 1. Hysteresis input.	
12	15	9	P31	В	General purpose I/O port of CMOS type.	
21	42	7	Vcc	_	Power supply pin.	
8,22	8, 19, 43	6,43	Vss	_	Power supply pin (GND). Use the both pins at the same voltage level.	
	27	20	AVcc	_	A/D converter power supply pin. Apply potential under Vcc to this pin.	
	28	19	AVss	_	A/D converter power supply pin (GND). Use at the same voltage level as the Vss supply.	
7	7	_	С	_	This is the power supply stabilization capacitor pin for MB89F217 and MB89P215. Connect an external capacitor of 0.1 μ F. MB89215 is not internally connected. It is unnecessary to connect a capacitor.	
_	3 to 6, 12 to 14, 24, 26, 29 to 31, 48	18, 29 to 42, 44,45	N.C.	_	Internal connect pin. Be sure this pin is left open.	

*1 : FPT-30P-M02

*2: FPT-48P-M13

*3: MQP-48C-P02

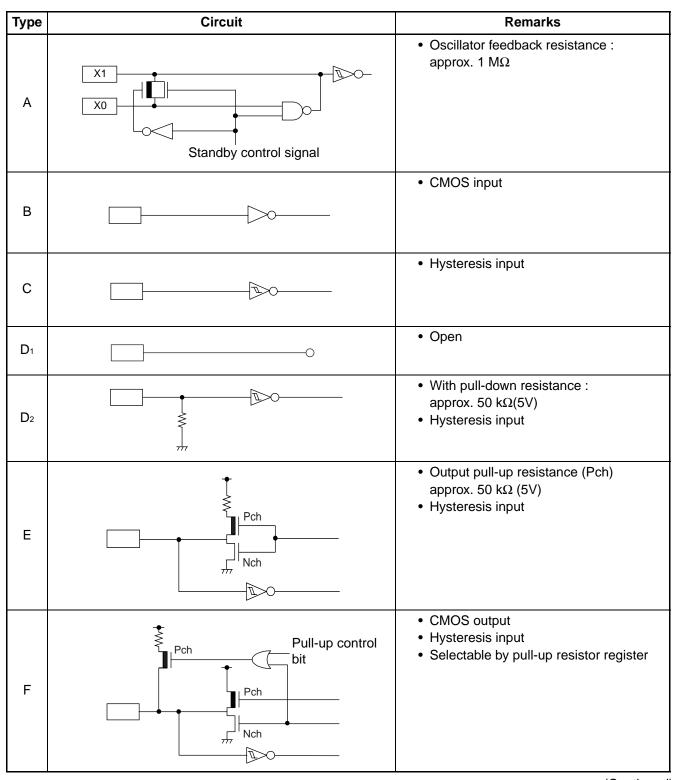
*4: MB89F217 is C.

*5: MB89F217 and MB89P215 are C.

■ EXTERNAL EPROM PIN DESCRIPTION (MB89PV210 only)

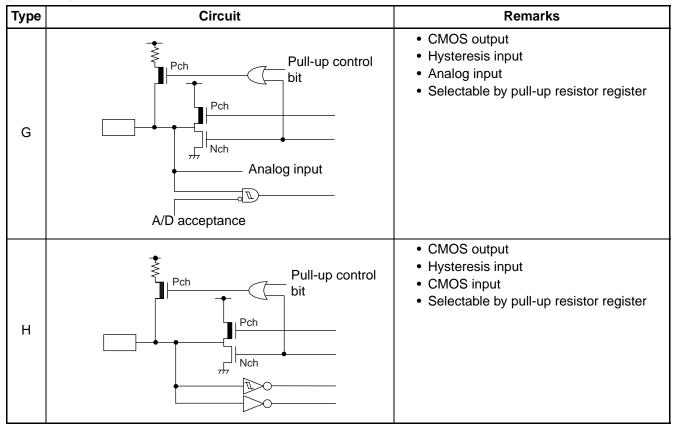
Pin no.	Pin name	I/O	Function
49	Vpp	0	"H" level output pin.
50 51 52 53 54 55 58 59 60	A12 A7 A6 A5 A4 A3 A2 A1 A0	0	Address output pin.
61 62 63	O1 O2 O3	Ι	Data input pin.
64	Vss	0	Power supply pin (GND).
65 66 67 68 69	O4 O5 O6 O7 O8	I	Data input pin.
70	CE	0	Chip acceptance pin for ROM. Output "H" at standby.
71	A10	0	Address output pin.
73	OE	0	Output acceptance pin for ROM. Output "L" usually.
75 76 77 78 79	A11 A9 A8 A13 A14	0	Address output pin.
80	Vcc	0	Power supply pin for EPROM.
56 57 72 74	N.C.	_	Internal connect pin. Must be left open.

■ I/O CIRCUIT TYPE



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HANDLING DEVICES

1. Preventing Latchup

Latchup may occur on CMOS ICs if voltage higher than Vcc or lower than Vss is applied to input or output pins other than the medium-and high-voltage pins or if voltage higher than the rating is applied between Vcc and Vss.

When latchup occurs, power supply current increases rapidly and might thermally damage elements. When using, take great care not to exceed the absolute maximum ratings.

Also, take care to prevent the analog input from exceeding the digital power supply (Vcc) when the analog system power supply is turned on and off.

To supply power, turn on the digital power supply (Vcc) and then the analog power supply (AVcc).

2. Treatment of Unused Input Pins

Leaving unused input teminals open may lead to permanent damage due to malfunction and latchup; pull up or pull down the terminals through the resistors of 2 $k\Omega$ or more.

Make the unused I/O terminal in a state of output and leave it open and if it is in an input state, handle it with the same procedure as the input terminals.

3. Treatment of N.C. Pins

Any pins marked "NC" (not connected) must be left open.

4. Power Supply Voltage Fluctuations

Although Vcc power supply voltage is assured to operate within the rated range, a rapid fluctuation of the voltage could cause malfunctions even if it occurs within the rated range. Stabilizing voltage supplied to the IC is therefore important. As stabilization guidelines, it is recommended to control power so that Vcc ripple fluctuations (P-P value) will be less than 10% of the standard Vcc value at the commercial frequency (50 to 60 Hz) and the transient fluctuation rate will be less than 0.1 V/ms.

5. Treatment of power supply pin

All Vss power suppluy pin must be use at the same voltage level.

Connect to be AVcc = Vcc, AVss = Vss even if the A/D converters are not in use in MB89PV210.

6. Notes on Using External Clock

When an external clock is used, oscillation stabilization time is required for even power-on reset and release from stop mode.

7. Notes on using the CR (internal) oscillator

To use the CR (internal) oscillator as the operating clock for the MB89215, MB89F217 or MB89P215, adjust the timer value and baud rate setting.

8. Program Execution in RAM

When the MB89PV210 is used with an emulation pod other than the MB2144-508, no program can be executed in RAM.

9. Operation check for evaluating the LIN-UART

When the MB89215, MB89F217 or MB89P215 uses the CR (internal) oscillator as the clock for the LIN-UART, the evaluation program (MB89PV210 [customized for external oscillation]) requires an operation check within a range of oscillation frequencies from 8.5 MHz to 11.5 MHz.

10. Handling reset pin

Reset pin must be inputted external reset.

11. Up/down conversion circuit stabilization waiting time

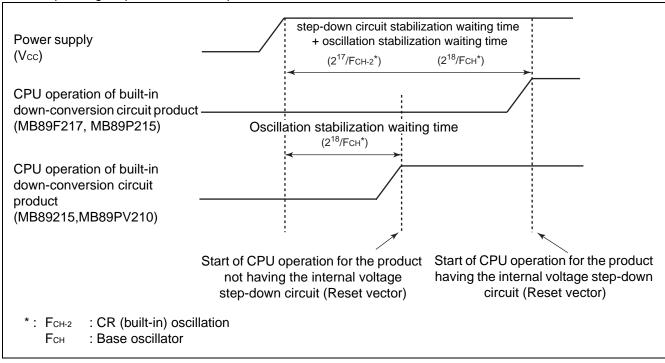
MB89210 series contains the following products and the operating characteristics vary with whether they contain the internal stepdown circuit.

Product name	Operating voltage *	Down conversion
MB89215	3.5 V to 5.5 V	not built-in
MB89F217	3.5 V to 5.5 V	built-in
MB89P215	3.5 V to 5.5 V	built-in
MB89PV210	3.5 V to 5.5 V	not built-in

^{*:} The minimum operating voltage varies with the operating frequency, the function and the connected ICE.

The same built-in resources are used for the above product types; operating sequences after the power-on reset are different depending on whether they have the internal voltages step-down circuit.

The operating sequences after the power-on reset with the different models will be described below.



As described above, CPU starts at delayed time with the product having the internal voltage step-down circuit compared with the product not having the internal voltage step-down circuit. This is because the time should be allowed for the stabilization time for voltage step-down circuit for normal operation.

Note: As the period of the oscillation is unstable immediately after oscillation starts, the listed oscillation stabilization delay times are guides only.

12. Treatment of analog input

The analog input also serves as a general-purpose input/output port. The A/D enable register is initialized at a reset. When the intermediate-level signal is input in port input mode (ADEN:ADEx = 0), an input leakage current flows to the gate. Set the corresponding pin to an analog input.

■ PROGRAMMING AND ERASING FLASH MEMORY ON THE MB89F217

1. Flash Memory

The flash memory is located between 8000_H and FFFF_H in the CPU memory map and incorporates a flash memory interface circuit that allows read access and program access from the CPU to be performed in the same way as mask ROM. Programming and erasing flash memory is also performed via the flash memory interface circuit by executing instructions in the CPU. This enables the flash memory to be updated in place under the control of the CPU, providing an efficient method of updating program and data.

2. Flash Memory Features

- 32 K byte × 8-bit configuration: (16 K + 8 K + 8 K sectors)
- Automatic programming algorithm (Embedded algorithm*: Equivalent to MBM29LV200)
- Includes an erase pause and restart function
- Data polling and toggle bit for detection of program/erase completion
- Detection of program/erase completion via CPU interrupt
- Compatible with JEDEC-standard commands
- Sector Erasing (sectors can be combined in any combination)
- No. of program/erase cycles: 10,000 (Min)
- *: Embedded Algorithm is a trademark of Advanced Micro Devices.

3. Procedure for Programming and Erasing Flash Memory

Programming and reading flash memory cannot be performed at the same time. Accordingly, to program or erase flash memory, the program must first be copied from flash memory to RAM so that programming can be performed without program access from flash memory.

4. Flash Memory Register

• Control status register (FMCS)

	bit7	bit6	bit5	bit4	bit3	bit2	bit1	bit0	
Address 007A _H	INTE	RDYINT	WE	RDY	Reserved	Reserved	-	Reserved	Initial value 0 0 0 X 0 0 - 0 _B
	R/W	R/W	R/W	R	R/W	R/W	-	R/W	

5. Sector Configuration

The table below shows the sector configuration of flash memory and lists the address of each sector for both during CPU access a flash memory programming.

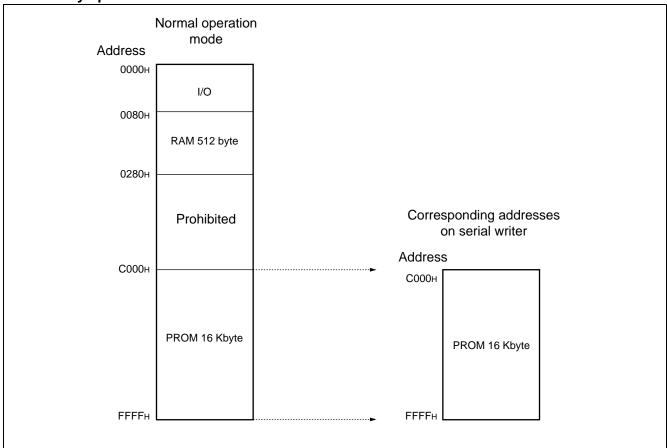
Sector configuration of flash memory

FLASH Memory	CPU Address	Programming Address*		
16 K bytes	FFFF _H to C000 _H	1FFFFн to 1С000н		
8 K bytes	BFFFн to A000н	1BFFFн to 1A000н		
8 K bytes	9FFFн to 8000н	19FFFн to 18000н		

^{* :} The programmer address is the address to be used instead of the CPU address when programming data from a parallel flash memory programmer. Use the programmer address on programming or erasing using a general-purpose parallel programmer.

■ PROGRAMMING TO OTPROM ON THE MB89P215

Memory space



2. Programming to the OTPROM

To program to the OTPROM using an EPROM programmer AF220/AF210/AF120/AF110 (manufacturer: Yokogawa Digital Computer Corp.).

Inquiry: Yokogawa Digital Computer Corp.: TEL(81)-42-333-6224

Note: Programming to the OTPROM with MB89P215 is serial programming mode only.

3. Programming Adaptor for OTPROM

To program to the OTPROM using an EPROM programmer AF220/AF210/AF120/AF110, use the programming adapter (manufacturer : Sunhayato Corp.) listed below.

Adaptor socket: ROM3-FPT30M02-8L3

Inquiry: Sunhayato Corp.: TEL: (81)-3-3984-7791

FAX: (81)-3-3971-0535

E-mail: adapter@sunhayato.co.jp

4. Programming yields

All bits cannot be programmed at Fujitsu shipping test to a blanked OTPROM microcomputer, due to its nature. For this reason, a programming yield of 100% cannot be assured at all times.

■ EPROM WRITING TO PIGGY-BACK/EVALUATION CHIPS

1. EPROM model

MBM27C256A-20TVM

2. Writer adapter

For writing to EPROM using a ROM writer, use one of the writer adapters shown below (manufactured by Sunhayato) .

Package	Adapter socket model		
LCC-32	ROM-32LC-28DP-S		

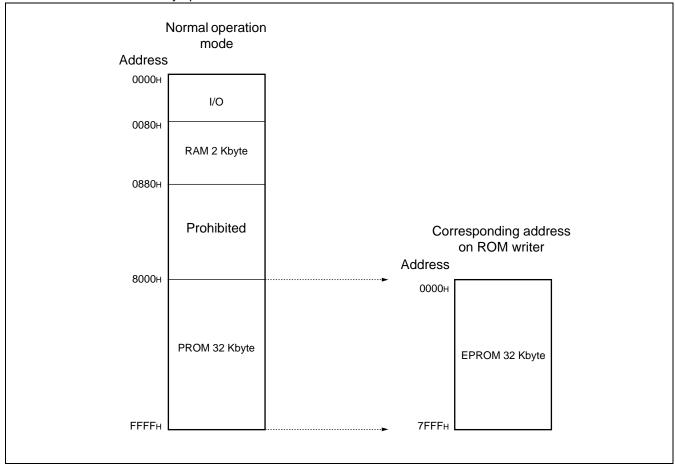
Inquiries should be addressed to Sunhayato Corp. : TEL : (81)-3-3984-7791

FAX : (81)-3-3971-0535

E-mail: adapter@sunhayato.co.jp

3. Memory space

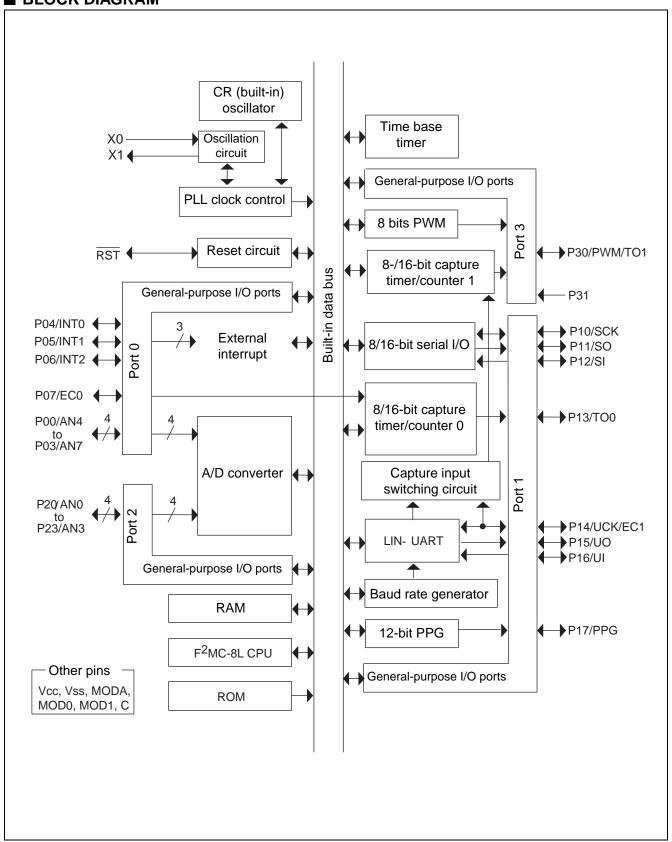
Shown below the memory space in each mode.



4. Writing to EPROM

- (1) Set up the EPROM writer for the MBM27C256A.
- (2) Load program data on to the EPROM programmer at 0000H to 7FFFH.
- (3) Program 0000H to 7FFFH with the EPROM programmer.

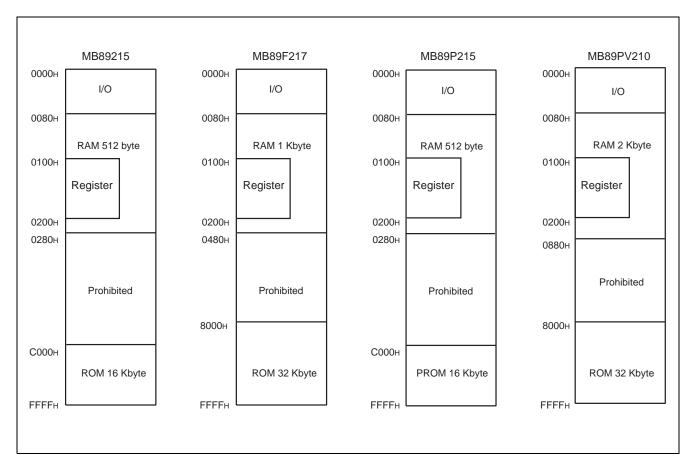
■ BLOCK DIAGRAM



■ CPU CORE

1. Memory space

The MB89210 series has 64 KB of memory space, containing all I/O, data areas, and program areas. The I/O area is located at the lowest addresses, with the data area placed immediately above. The data area can be partitioned into register areas, stack areas, or direct access areas depending on the application. The program area is located at the opposite end of memory, closest to the highest addresses, and the highest part of this area is assigned to the tables of interrupt and reset vectors and vector call instructions. The following diagram shows the structure of memory space in the MB89210 series.



2. Register

The MB89210 series has two types of registers; the registers dedicated to specific purposes in the CPU and the general-purpose registers. The dedicated registers are as follows:

Program counter (PC) : 16-bit length, shows the locations where instructions are stored.

Accumulator (A) : 16-bit length, a temporary memory register for calculation operations. In the

case of an 8-bit data processing instruction, the lower one byte is used.

Temporary accumulator (T) : 16-bit length, performs calculations with the accumulator. In the case of an

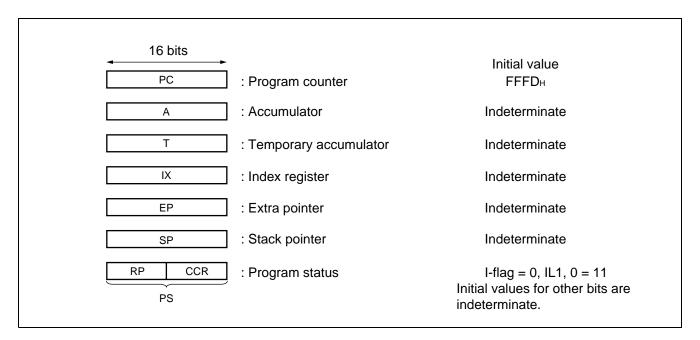
8-bit data processing instruction, the lower one byte is used.

Index register (IX) : 16-bit length, a register for index modification.

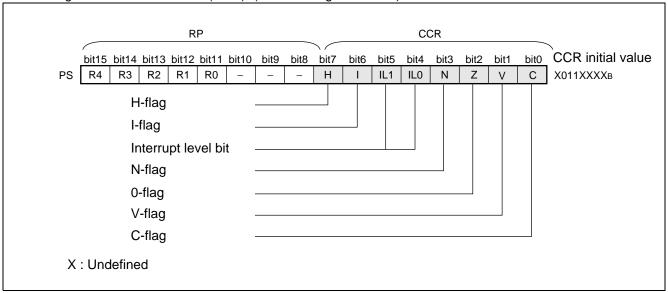
Extra pointer (EP) : 16-bit length, apointer indicating memory addresses.

Stack pointer (SP) : 16-bit length, indicates stack areas.

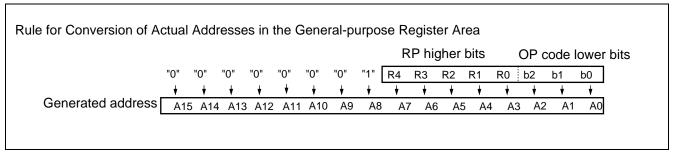
Program status (PS) : 16-bit length, contains register pointer and condition code.



The PS register can further be divided into the register bank pointer in the higher 8 bits (RP) and the condition code register in the lower 8 bits (CCR). (See the diagram below.)



The RP points to the address of the register bank currently in use. The relationship between the pointer contents and the actual address is based on the conversion rule shown next.



The CCR consists of the bits indicating arithmetic operation results or transfer data contents and the bits that control CPU operations at the time of an interrupt.

H flag : Set to 1 if calculations result in carry operations from bit 3 to bit 4 or borrow operations from bit 4

to bit 3, otherwise set to 0.

The flag is for decimal adjustment instructions; do not use for other than additions and subtractions.

This flag is set to 1 if interrupts are enabled, and 0 if interrupts are prohibited. The default value at

reset is 0.

I flag

IL1, 0 : Indicates the level of the interrupt currently enabled.

An interrupt is processed only if its level is higher than the value this bit indicates.

IL1	IL0	Interrupt level	High-low
0	0	1	Higher
0	1	1	<u>†</u>
1	0	2	↓
1	1	3	Lower = no interruption

N flag : Set to 1 if the highest bit is 1 after a calculation, otherwise cleared to 0.

Z flag : Set to 1 if a calculation result is 0, otherwise cleared to 0.

V flag : Set to 1 if a 2's complement overflow results during a calculation, otherwise cleared to 0.

C flag : Set to 1 if a calculation results in a carry or borrow operation from bit 7, otherwise cleared to 0.

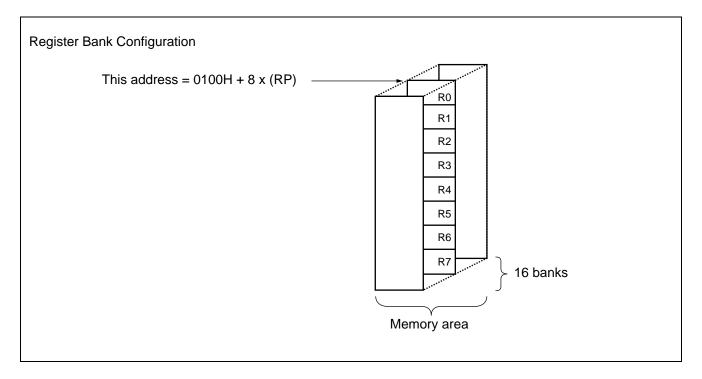
This is also the shift-out value in a shift instruction.

The following general-purpose registers are provided:

General-purpose registers: 8-bit length, data storage registers

The general-purpose registers are 8 bits in length and located in the register banks in the memory. One bank contains eight registers and the MB89210 series allow a total of 16 banks to be used at maximum.

The bank currently in use is indicated by the register bank pointer (RP).



■ I/O MAP

Address	Register name	Register description	Read/write	Initial value					
0000н	PDR0	Port 0 data register	R/W	XXXXXXXX					
0001н	DDR0	Port 0 direction register	R/W	00000000					
0002н to 0006н	Access prohibited								
0007н	SYCC	System clock control register	R/W	111100					
0008н	STBC	Standby control register	R/W	00010					
0009н	WDTC	Watchdog timer control register	W	0XXXX					
000Ан	TBTC	Time base timer control register	R/W	00000					
000Вн		Access prohibited							
000Сн	PDR1	Port 1 data register	R/W	XXXXXXXX					
000Дн	DDR1	Port 1 direction register	R/W	00000000					
000Ен	RSFR	Reset flag register	R	XXXX					
000Fн	PDR2	Port 2 data register	R/W	XXXX					
0010н	DDR2	Port 2 direction register	R/W	0000					
0011н		Access prohibited	•						
0012н	PDR3	Port 3 data register	R/W	XX					
0013н	DDR3	Port 3 direction register	R/W	0					
0014н	RCR21	12-bit PPG control register 1	R/W	00000000					
0015н	RCR22	12-bit PPG control register 2	R/W	000000					
0016н	RCR23	12-bit PPG control register 3	R/W	0-000000					
0017н	RCR24	12-bit PPG control register 4	R/W	000000					
0018н		Access prohibited	•						
0019н	TCCR0	Capture control register 0	R/W	00000000					
001Ан	TCR10	Timer 1 control register 0	R/W	000-0000					
001Вн	TCR00	Timer 0 control register 0	R/W	00000000					
001Сн	TDR10	Timer 1 Data 0	R/W	XXXXXXXX					
001Дн	TDR00	Timer 0 Data 0	R/W	XXXXXXXX					
001Ен	TCPH0	Capture data register H 0	R	XXXXXXXX					
001Гн	TCPL0	Capture data register L 0	R	XXXXXXXX					
0020н	TCR20	Timer output control 0	R/W	00					
0021н	Access prohibited								
0022н	CNTR	PWM control register	R/W	0-000000					
0023н	COMR	PWM Compare register	W	XXXXXXXX					
0024н	EIC1	External interrupt control register 1 (edge)	R/W	00000000					
0025н	EIC2	External interrupt control register 2 (edge)	R/W	00000000					

(Continued)

Address	Register name	Register description	Read/write	Initial value
0026н		^	-	
0027н		Access prohibited		
0028н	SCR	Serial control register	R/W	00000000
0029н	USMR	LIN-UART serial mode register	R/W	00000000
002Ан	SSR	Serial status register	R/W	00001000
0000	RDR	Recieving data register	R	0000000
002Вн	TDR	Sending data register	W	11111111
002Сн	ESCR	Extended status control register	R/W	00000X00
002Dн	ECCR	Extended communication control register	R/W	00000-11
002Ен	BGRH	Baud rate generator register H	R/W	-0000000
002Fн	BGRL	Baud rate generator register L	R/W	00000000
0030н	ADC1	A/D control register 1	R/W	00000000
0031н	ADC2	A/D control register 2	R/W	00000001
0032н	ADDH	A/D data register H	R/W	000000XX
0033н	ADDL	A/D data register L	R/W	XXXXXXXX
0034н	ADEN	A/D enable register	R/W	0000000
0035н to 0038н		Access prohibited		
0039н	SMR	Serial mode register	R/W	00000000
003Ан	SDR	Serial Data register	R/W	xxxxxxxx
003Вн to 0040н		Access prohibited		
0041н	TCCR1	Capture control register 1	R/W	00000000
0042н	TCR11	Timer 1 control register 1	R/W	000-0000
0043н	TCR01	Timer 0 control register 1	R/W	00000000
0044н	TDR11	Timer 1 Data register 1	R/W	XXXXXXXX
0045н	TDR01	Timer 0 Data register 1	R/W	XXXXXXXX
0046н	TCPH1	Capture status register H1	R	XXXXXXXX
0047н	TCPL1	Capture status register L1	R	XXXXXXXX
0048н	TCR21	Timer output control register 1	R/W	00
0049н	TCSL	Capture input select register	R/W	0
004Ан to 005Fн		Access prohibited		
0060н	XCRS*	External/CR(built-in)oscillation clock control register	R/W	00-00010
0061н to 006Fн		Access prohibited	1	1

(Continued)

(Continued)

Address	Register name	Register description	Read/write	Initial value				
0070н	PUL0	Port 0 pull-up setting register	R/W	00000000				
0071н	PUL1	Port 1 pull-up setting register	R/W	00000000				
0072н	PUL2	Port 2 pull-up setting register	R/W	0000				
0073н	PUL3	Port 3 pull-up setting register	R/W	0				
0074н to 0079н		Access prohibited						
007Ан	FMCS	Flash memory control status register	R/W	000000-0				
007Вн	ILR1	Interrupt level setting register 1	W	11111111				
007Сн	ILR2	Interrupt level setting register 2	W	11111111				
007Dн	ILR3	Interrupt level setting register 3	W	11111111				
007Ен	ILR4	Interrupt level setting register 3	W	11111111				
007Fн	Access prohibited							

^{*:} Only for MB89215, MB89F217, MB89P215

Description of write/read symbols:

R/W: Read/write enabled

R : Read only W : Write only

Description of initial values

0 : This bit initialized to "0".1 : This bit initialized to "1".

X: The initial value of this bit is undefined.

- : This bit is not defined.

Note: If a bit manipulation instruction accesses the serial mode register (SMR), a write-only register, or a register containing a write-only bit, the bit focused on by the instruction is set to a prescribed value but a malfunction occurs when the other bits contains a write-only bit. Do not use bit manipulation instructions to access such registers.

■ ELECTRICAL CHARACTERISTICS

1. Absolute Maximum Ratings

Parameter	Cumbal	Rat	ing	Unit	Remarks
Parameter	Symbol	Min	Max	Unit	Remarks
Power supply voltage	Vcc	Vss - 0.3	Vss + 6.0	V	
Input voltage	Vı	Vss - 0.3	Vcc + 0.3	V	*2
Output voltage	Vo	Vss - 0.3	Vss + 6.0	V	
Maximum clamp current	ICLAMP	- 0.4	+ 0.4	mA	*1
Maximum clamp total current	$\Sigma I_{CLAMP} $	_	10	mA	*1
"L" level output current	lol	_	10	mA	
"L" level average current	lolav		4	mA	Average value (operating current × operating duty)
"L" level total output current	Σ loL		50	mA	
"H" level output current	Іон	_	- 10	mA	
"H" level average current	Іонач	_	- 4	mA	Average value (operating current × operating duty)
"H" level total output current	ΣІон	_	- 50	mA	
Dower consumption	Pd	_	200	mW	MB89215, MB89P215
Power consumption	Pu	_	300	mW	MB89F217
Storage temperature	Tstg	– 55	+ 150	°C	

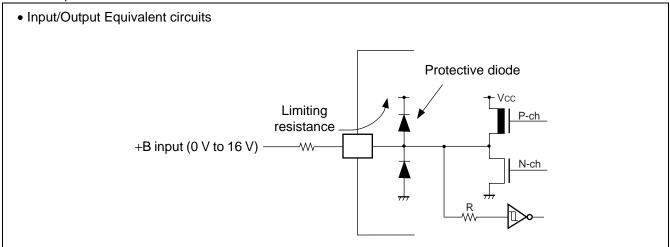
^{*1: •} Applicable to pins: P00 to P07, P10 to P17, P20 to P23, P30 to P31

- Use within recommended operating conditions.
- Use at DC voltage (current) .
- The +B signal should always be applied with a limiting resistance placed between the +B signal and the microcontroller.
- The value of the limiting resistance should be set so that when the +B signal is applied the input current to the microcontroller pin does not exceed rated values, either instantaneously or for prolonged periods.
- Note that when the microcontroller drive current is low, such as in the power saving modes, the +B input potential may pass through the protective diode and increase the potential at the Vcc pin, and this may affect other devices.
- Note that if a +B signal is input when the microcontroller current is off (not fixed at 0 V), the power supply is provided from the pins, so that incomplete operation may result.
- Note that if the +B input is applied during power-on, the power supply is provided from the pins and the resulting supply voltage may not be sufficient to operate the power-on reset.
- Care must be taken not to leave the +B input pin open.
- Note that analog system input/output pins other than the A/D input pins (LCD drive pins, comparator input pins, etc.) cannot accept +B signal input.

(Continued)

(Continued)

• Sample recommended circuits :

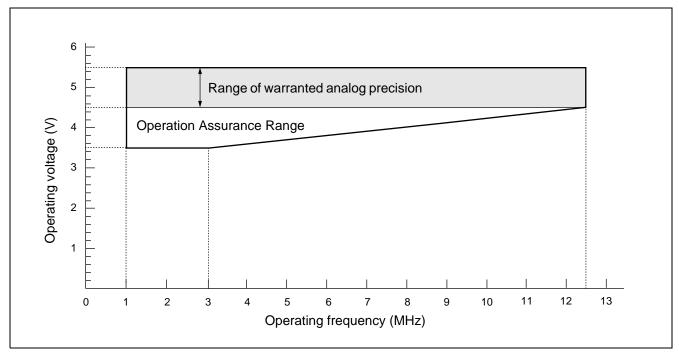


*2 : If the maximum current to/from an input is limited by some means with external components, the Iclamp rating supersedes the V_I rating.

WARNING: Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

2. Recommended Operating Conditions

Parameter	Symbol	Va	lue	Unit	Remarks
Parameter	Symbol	Min	Max	Onit	Remarks
Power supply voltage	Vcc	3.5	5.5	V	Normal Operation Assurance Range
		3.0	5.5	V	RAM status in stop mode
	ViH	0.7 Vcc	Vcc + 0.3	V	P31,UI
Input "H" voltage	Vihs	0.8 Vcc	Vcc + 0.3	V	MODA, MOD0, MOD1, RST, P00 to P07, P10 to P17, P20 to P23, P30, INT0 to INT2, EC0, EC1, SCK, SI, UCK
	VIL	Vss - 0.3	0.3 Vcc	V	P31,UI
Input "L" voltage	VILS	Vss - 0.3	0.2 Vcc	٧	MODA, MOD0, MOD1, RST, P00 to P07, P10 to P17, P20 to P23, P30, INT0 to INT2, EC0, EC1, SCK, SI, UCK
Operating temperature	Та	- 40	+ 105	°C	



WARNING: The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the device's electrical characteristics are warranted when the device is operated within these ranges.

Always use semiconductor devices within their recommended operating condition ranges. Operation outside these ranges may adversely affect reliability and could result in device failure.

No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their FUJITSU representatives beforehand.

3. DC Characteristics

(Vcc = 5.0 V \pm 10%, Vss = 0.0 V, FcH = 10 MHz (external clock), Ta = -40 °C to +105 °C)

D			D'	0 1111		Value	<u>·</u>	1114	
Parameter	Symbol		Pin name	Condition	Min	Тур	Max	Unit	Remarks
	Vih	P31,	UI	_	0.7 Vcc	_	Vcc + 0.3	V	
"H" level input voltage	Vins	RST P10 P30,	DA, MOD0, MOD1, , P00 to P07, to P17,P20 to P23, INT0 to INT2, EC0, , SCK, SI, UCK	_	0.8 Vcc	_	Vcc + 0.3	V	
	VIL	P31,	UI	_	Vss - 0.3		0.3 Vcc	V	
"L" level input voltage	VILS	RST P10 P30,	DA, MOD0, MOD1, , P00 to P07, to P17,P20 to P23, INT0 to INT2, EC0, , SCK, SI, UCK	_	Vss-0.3	_	0.2 Vcc	V	
"H" level output voltage	Vон		to P07, P10 to P17, to P23, P30	Vcc = 4.5 V, IoH = -4.0 mA	Vcc – 0.5	_	_	V	
"L" level output voltage	Vol		to P07, P10 to P17, to P23, P30, RST	Vcc = 4.5 V, IoL = 4.0 mA	_		0.4	V	
Input leak current	lu	P20	to P07, P10 to P17, to P23, P30, P31, DA, MOD0, MOD1	0.45 V < Vı < Vcc	_		± 5	μΑ	Without pull-up resistance specified
Pullup resistance	RPULL		to P07,P10 to P17, to P23, P30, RST	Vı = 0.0 V	25	50	100	kΩ	
					_	8	12	mΑ	MB89215
			At normal	When A/D convereter stops		6	10	mΑ	MB89F217
	laa		operating		_	6	9	mA	MB89P215
	Icc		(External clock,		_	10	15	mA	MB89215
			Max gear speed)	When A/D convereter starts		8	13	mA	MB89F217
Power supply		Vcc				8	12	mA	MB89P215
current			at sleep mode	When A/D	_	4	6	mΑ	MB89215
	Iccs		(External clock, Max gear speed)	convereter stops	_	3	5	mA	MB89F217, MB89P215
			At stop mode	When A/D	_	_	1	μΑ	MB89215
	Іссн		Ta = +25 °C (External clock)	convereter stops	_	_	10	μΑ	MB89F217, MB89P215
Input capacitance	Cin	Othe	er than Vcc and Vss			5	15	pF	MB89F217, MB89P215

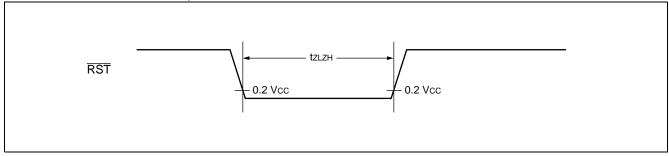
4. AC Characteristics

(1) Reset Timing

$$(Vss = 0.0 V, Ta = -40 °C to +105 °C)$$

Parameter	Symbol	Condition	Va	lue	Unit	Remarks
Farameter	Syllibol	Condition	Min	Max	Offic	Kemarks
RST "L" level pulse width	t zlzh	_	48 thcyl*	_	ns	

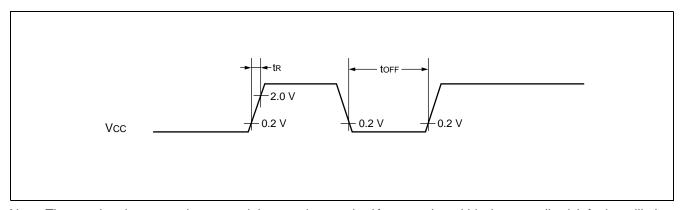
*: they : Oscillation clock one cycle time



(2) Power-on reset

$$(Vss = 0.0 V, Ta = -40 °C to +105 °C)$$

Parameter	Symbol	Condition	Va	lue	Unit	Remarks
	Symbol	Condition	Min	Max	Onne	Remarks
Power on time	t R	_	_	50	ms	
Power shutoff time	toff	_	1	_	ms	For repeated operation



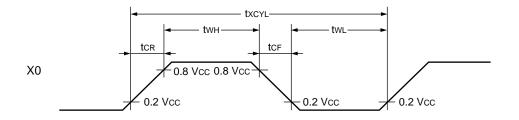
Note: The supply voltage must be set to minimum value required for operation within the prescribed default oscillation setting time.

(3) Clock Timing

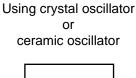
$$(Vss = 0.0 \text{ V}, Ta = -40 ^{\circ}\text{C to} +105 ^{\circ}\text{C})$$

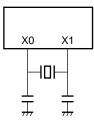
Parameter	Symbol	Condition	Va	lue	Unit	Remarks
Faranietei	Зуппоп	Condition	Min	Max	Oilit	Nemarks
Clock frequency	FcH-1		1	12.5	MHz	
Clock cycle time	txcyL	Crystal or - ceramic oscillation	80	1000	ns	
Input clock pulse width	twн twL		20	_	ns	
Input clock rise, fall time	tcr tcf		_	10	ns	
Oscillation frequency	F _{CH-2}	CR(built-in) oscillator	8.5	11.5	MHz	

• X0 and X1 Timing and application Conditions

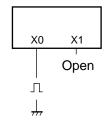


• Clock application Conditions

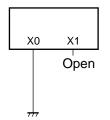








Using CR (built-in) oscillator



(4) Instruction Cycle

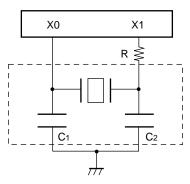
$$(Vss = 0.0 V, Ta = -40 °C to +105 °C)$$

Parameter	Symbol	Value	Unit	Remarks
Instruction cycle (instruction execution time)	t INST	4/Fсн, 8/Fсн, 16/Fсн, 64/Fсн	l IIS	When operating at FcH = 10 MHz tinst = 0.4 μs (4/FcH)

Fch: Oscillation frequency (Operating clock frequency after switching between external and CR (internal) oscillator clocks)

(5) Recommended Resonator Manufactures

Sample application of ceramic resonator



Resonator manufacture	Resonator	Frequency (MHz)	C ₁	C ₂	R
	CSTLS4M00G56-B0	4.00	built-in	built-in	680 Ω
	CSTCR4M00G55-R0	4.00	built-in	built-in	680 Ω
Murata Mfg. Co., Ltd.	CSTLS8M00G53-B0	8.00	built-in	built-in	_
Muraia Wilg. Co., Liu.	CSTCC8M00G53-R0	8.00	built-in	built-in	_
	CSTLS10M0G53-B0	10.00	built-in	built-in	_
	CSTCC10M00G53-R0	10.00	built-in	built-in	_

Inquiry: • Murata Electronics North America Inc : TEL +1-404-436-1300

• Murata Europe Management GmbH : TEL +49-911-66870

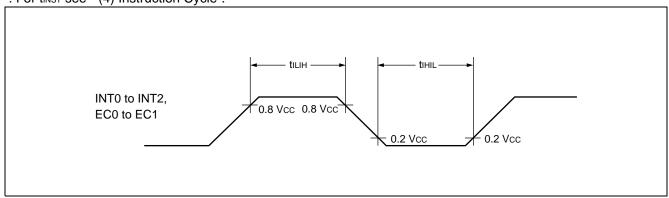
• Murata Electronics Singapore (p/e) : TEL +65-758-4233

(6) Peripheral Input Timing

(Vcc = 5.0 V \pm 10%, Vss = 0.0 V, Ta = -40 °C to +105 °C)

Parameter	Symbol	Pin name	Value		Unit	Remarks
Parameter	Syllibol	riii iiaiiie	Min	Max	Oilit	iveillai ks
Peripheral input "H" pulse width	t ılıH	INT0 to INT2,	2 t INST*		μs	
Peripheral input "L" pulse width	tıнıL	EC0, EC1	2 tinst*		μs	

*: For tinst see " (4) Instruction Cycle".

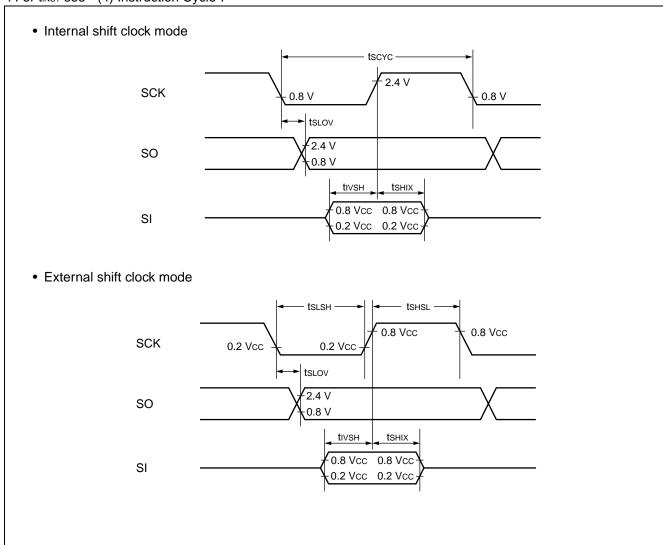


(7) Serial I/O Timing

 $(Vcc = 5.0 \text{ V} \pm 10\%, \text{ Vss} = 0.0 \text{ V}, \text{ Ta} = -40 \text{ }^{\circ}\text{C to} +105 \text{ }^{\circ}\text{C})$

Parameter	Symbol	Pin name	Condition	Val	ue	Unit	Remarks
raiametei	Symbol	Fill Hallie	Condition	Min	Max	Oilit	Remarks
Serial clock cycle time	tscyc	SCK		2 tinst*	_	μs	
$SCK \downarrow \to SO$ time	tslov	SCK, SO	Internal clock operation	- 200	200	ns	
Valid SI → SCK ↑	tıvsн	SCK, SI		0.5 tinst*	_	μs	
$SCK \uparrow \to Valid \; SI \; hold \; time$	t sнıx	SCK, SI		0.5 tinst*	_	μs	
Serial clock "H" pulse width	t shsl	SCK		tinst*		μs	
Serial clock "L" pulse width	t slsh	SCK	External	tinst*		μs	
$SCK \downarrow \to SO$ time	tslov	SCK, SO	clock	0	200	ns	
Valid SI → SCK ↑	tıvsн	SCK, SI	operation	0.5 tinst*		μs	
$SCK \uparrow \rightarrow Valid SI hold time$	t sнıx	SCK, SI		0.5 t _{INST} *		μs	

*: For tinst see " (4) Instruction Cycle".

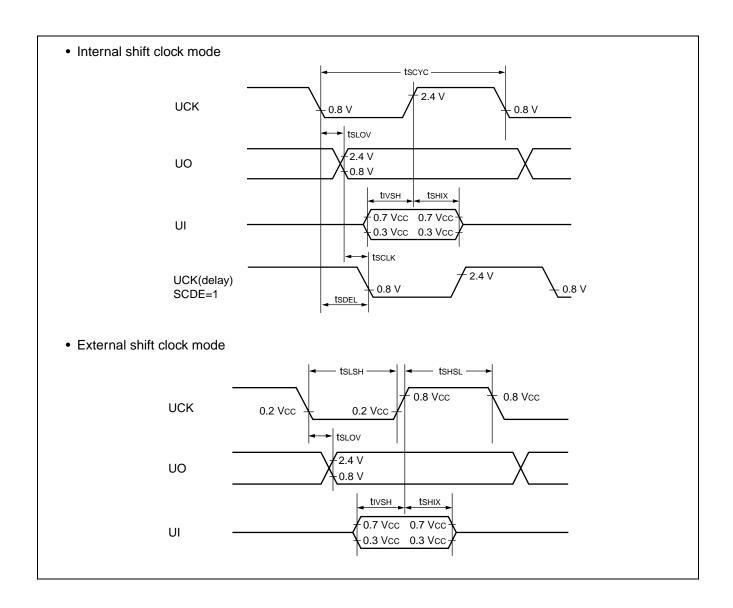


(8) LIN-UART timing

(Vcc = 5.0 V \pm 10%, Vss = 0.0 V, Ta = -40 °C to +105 °C)

Parameter	Symbol	Pin name	Condition	Value		Unit	Remarks
Parameter	Symbol	Pili name	Condition	Min	Max	Offic	Remarks
Serial clock cycle time	tscyc	UCK		2 tinst*	_	μs	
$UCK\downarrow \to UO$ time	t sLOV	UCK, UO		- 200	200	ns	
Valid UI → UCK ↑	t ıvsh	UCK, UI		0.5 t _{INST} *		μs	
$UCK \uparrow \to Valid \; UI \; hold \; time$	t sнıx	UCK, UI	Internal	0	_	μs	
$UCK\downarrow \to UO$ time	t sLOV	UCK, UO	clock operation	- 200	200	ns	SCDE = 1
UCK (delay) \downarrow \rightarrow UO time	t sclk	UCK (delay), UO	operation .	- 0.5 tinst*	_	μs	SCDE = 1
$UCK \downarrow \to UCK \ (delay) \downarrow$	tsdel	UCK, UCK (de- lay)		0.5 t _{INST} *	_	μs	SCDE = 1
Serial clock "H" pulse width	t shsl	UCK		1.5 t _{INST} *	_	μs	
Serial clock "L" pulse width	t slsh	UCK	External clock	1.5 t _{INST} *		μs	
$UCK\downarrow \to UO$ time	t sLOV	UCK, UO		tinst*	_	μs	
Valid UI → UCK ↑	t ıvsh	UCK, UI	operation	0		μs	
$UCK \uparrow \to Valid \; UI \; hold \; time$	t sнıx	UCK, UI		0.5 t _{INST} *	_	μs	

^{*:} For tinst see " (4) Instruction Cycle".



5. A/D Converter

(1) A/D converter electrical characteristics

(Vcc = 5.0 V + 10%, Vss = 0.0 V, Ta = $-40 \text{ }^{\circ}\text{C}$ to $+105 \text{ }^{\circ}\text{C}$)

Parameter	Symbol	Value				Remarks
Farameter		Min	Тур	Max	Unit	Remarks
Resolution		_	_	10	bit	
Total error		- 5.0	_	+ 5.0	LSB	
Linearity error]	- 3.0		+ 3.0	LSB	
Differential linear error		- 2.5	_	+ 2.5	LSB	
Zero transition voltage	Vот	Vss - 3.5 LSB	Vss + 0.5 LSB	Vss + 4.5 LSB	V	
Full-scale transition voltage	V _{FST}	Vcc – 6.5 LSB	Vcc – 1.5 LSB	Vcc + 2.0 LSB	V	
A/D mode conversion time		_	_	38 t INST*	μs	
Analog input current	lain	_	_	10	μΑ	
Analog input voltage range		0	_	Vcc	V	

^{*:} For tinst see " (4) Instruction Cycle" in "4. AC Characteristics".

(2) Definition of A/D Converter Terms

Resolution

The level of analog variation that can be distinguished by the A/D converter.

When the number of bits is 10, analog voltage can be divided into $2^{10} = 1024$.

• Linear error (Unit: LSB)

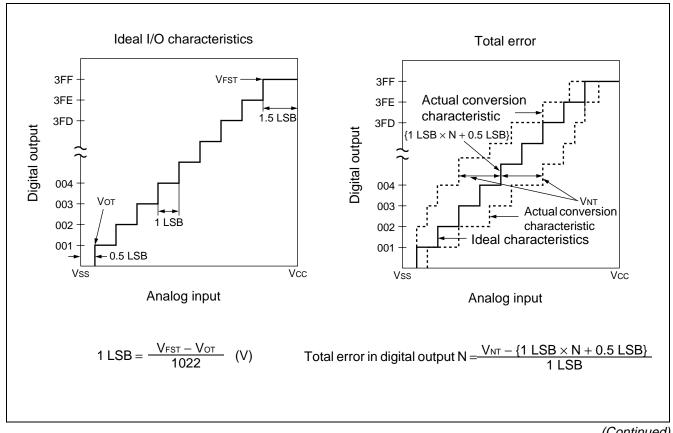
The deviation between the value along a straight line connecting the zero transition point("00 0000 0000° \longleftrightarrow 00 0000 0001°) of a device and the full-scale transition point ("11 1111 1111" \longleftrightarrow 11 1111 1110"), compared with the actual conversion values obtained.

• Differential linear error (Unit : LSB)

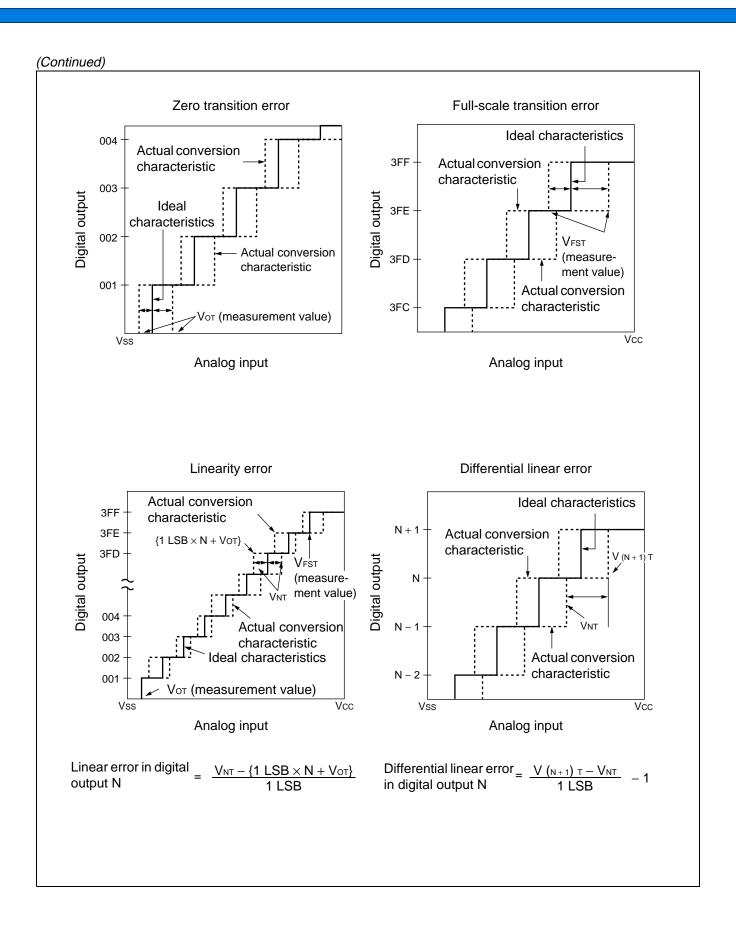
Deviation of input voltage, which is required for changing output code by 1 LSB, from an ideal value.

Total error (Unit : LSB)

The difference between theoretical conversion value and actual conversion value.



(Continued)

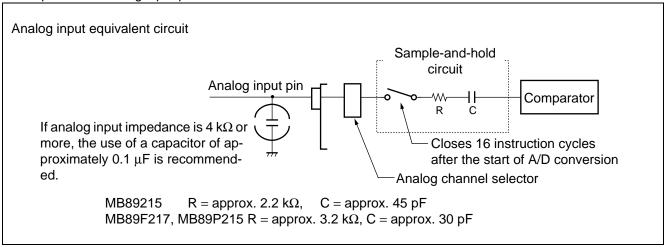


(3) Precautionary Information of A/D conversion

• Input Impedance of Analog Input Pins

The A/D converter has a sample & hold circuit as shown below, which uses a sample-and-hold capacitor to obtain the voltage at the analog input pin for 16 instruction cycles following the start of A/D conversion. For this reason if the external circuits providing the analog input signal have high output impedance, the analog input voltage may not stabilize within the analog input sampling time. It is therefore recommended that the output impedance of external circuits be reduced to $4 \text{ k}\Omega$ or less.

Note that if the impedance cannot be kept low, it is recommended to connect an external capacitor of about 0.1 μ F for the analog input pin.



About errors

The smaller the absolute value |Vcc - Vss| is, the greater the relative error becomes.

6. Electrical Characteristics of Flash Memory

• Programming and erasing characteristics

Parameter		Symbol	Pin Name	Condition	Value			Unit	Remarks	
r ai ainetei				Condition	Min	Тур	Max	Oill	ixemai ks	
Power supply current *1			IFWE	Vcc	Vcc = 5.0 V			40	mA	
Sector erase	Per 1 sector, constant value	Successful completion time	_		_	_	1	15	s	
time	independent with sector capacitance	Unsuccessful completion time	_	_	_			*2	_	
Programming Per 1 byte	Successful completion time	_	_	_		8	3600	μs		
time	r er i byte	Unsuccessful completion time			_		650	3600	μs	

^{*1:} Embedded Algorithm executing.

^{*2 :} If a fault occurs during sector erasing, detection via DQ_5 may not be available ($DQ_5 = 1$ may not occur) . Accordingly, a fault must be assumed after 15 s, even if DQ_5 does not go to "1".

■ MASK OPTIONS

No	Part number	MB89215	MB89F217	MB89P215	MB89PV210	
NO	Specifying procedure	Setting disallowed				
1	Initial value* selection of internal clock oscillation stabilization wait time (at FcH = 10 MHz) • 01 : 214/FcH (Approx. 1.63 ms) • 10 : 217/FcH (Approx. 13.1 ms) • 11 : 218/FcH (Approx. 26.2 ms)		2 ¹⁸ /Fch (App	rox. 26.2 ms)		
2	Power-on reset ON • Power-on reset OFF		Y	es		
3	Reset pin output Reset output ON Reset output OFF		Y	es		

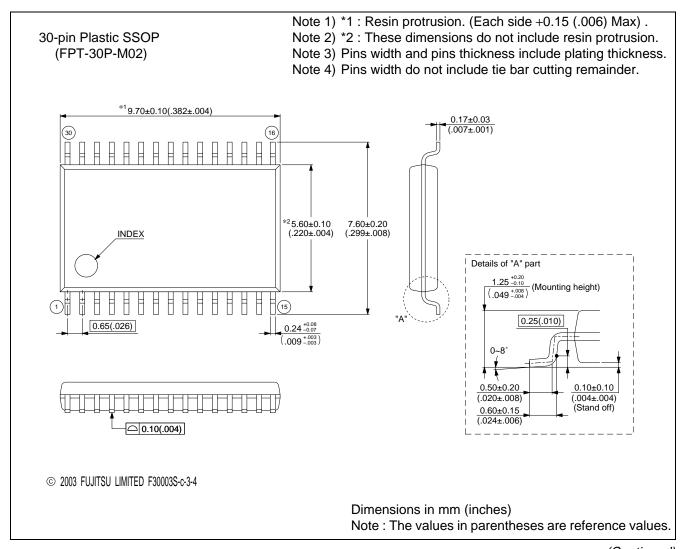
Fсн: Base oscillator

■ ORDERING INFORMATION

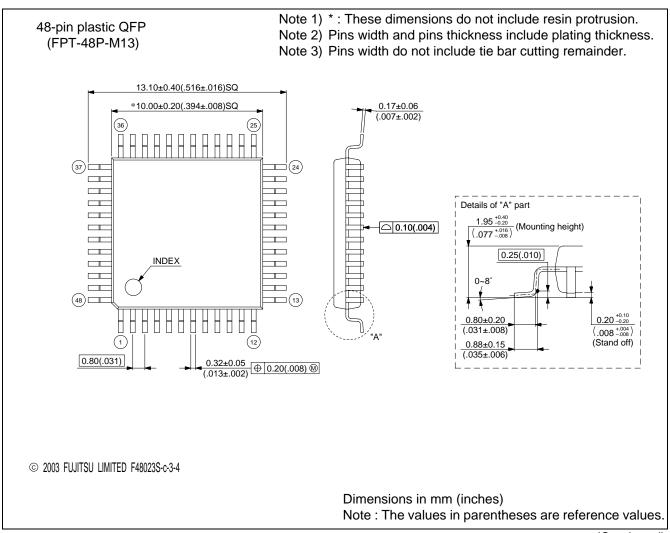
Part number	Package	Remarks		
MB89215PFV MB89P215PFV	30-pin Plastic SSOP (FPT-30P-M02)			
MB89215PFM MB89F217PFM	48-pin Plastic QFP (FPT-48P-M13)			
B89PV210CF 48-pin Ceramic MQFP (MQP-48C-P02)				

^{*:} Initial value to which the oscillation setting time bit (sync: WT1, WT0) in the system clock control register is set.

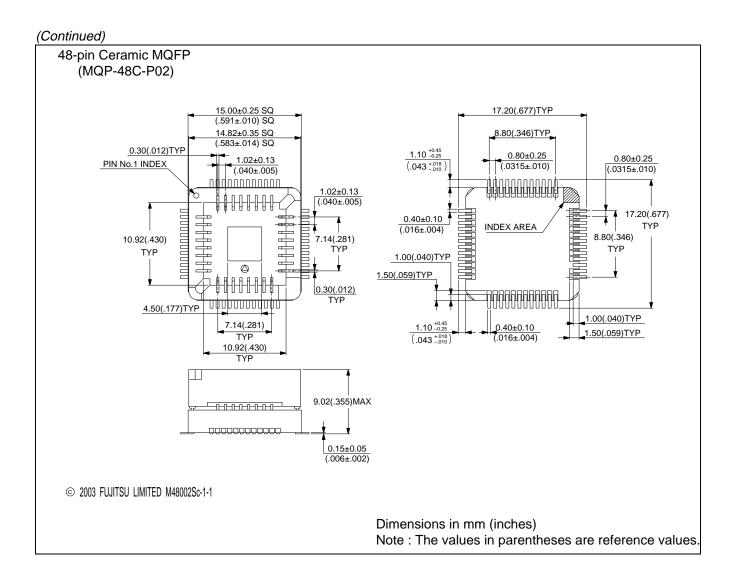
■ PACKAGE DIMENSIONS



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